

INJ0001AX SERIES

High speed switching
Silicon P-channel MOSFET

DESCRIPTION

INJ0001AX is a Silicon P-channel MOSFET.
This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low on resistance.

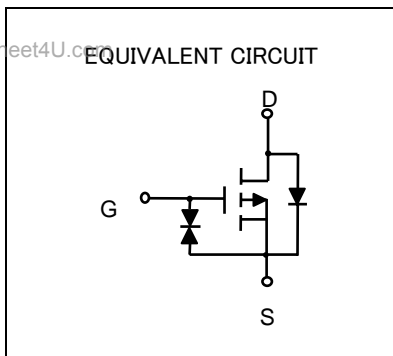
FEATURE

- Input impedance is high, and not necessary to consider a drive electric current.
- V_{th} is low, and drive by low voltage is possible. $V_{th} = -0.6 \sim -1.2V$
- Low on Resistance. $R_{on} = 7\Omega$ (TYP)
- High speed switching.
- Small package for easy mounting.

APPLICATION

high speed switching, Analog switching

OUTLINE DRAWING		Unit: mm
<p>JEITA, JEDEC: — ISAHAYA: T-USM</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	<p>JEITA: SC-70 JEDEC: —</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	
<p>JEITA: SC-75A JEDEC: —</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	<p>JEITA: SC-59 JEDEC: Similar to TO-236</p> <p>T TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	



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MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING				UNIT
		INJ0001AT2	INJ0001AU1	INJ0001AM1	INJ0001AC1	
V _{DSS}	Drain-source voltage	-50				V
V _{GSS}	Gate-source voltage	±8				V
I _D	Drain current	-100				mA
P _D	Total power dissipation (Ta=25°C)	125(※)	150	200		mW
T _{ch}	Channel temperature	+125	+150			°C
T _{stg}	Range of Storage temperature	-55~+125	-55~+150			°C

ELECTRICAL CHARACTERISTICS (Ta=25°C)

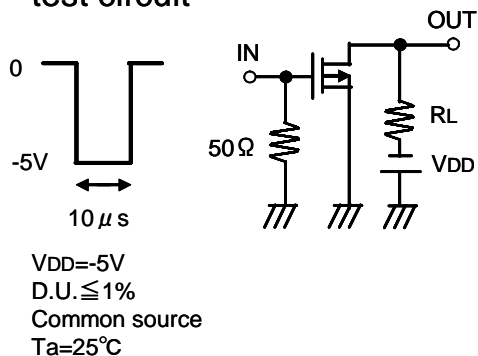
※package mounted on 9mm × 19mm × 1mm glass-epoxy substrate.

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
V _{(BR)DSS}	Drain-source breakdown voltage	I _D = -100 μA, V _{GS} = 0V	-50	-	-	V
I _{GSS}	Gate-source leak current	V _{GS} = ±5V, V _{DS} = 0V	-	-	±0.5	μA
I _{DSS}	Zero gate voltage drain current	V _{DS} = -50V, V _{GS} = 0V	-	-	-1.0	μA
V _{th}	Gate threshold voltage	I _D = -250 μA, V _{DS} = V _{GS}	-0.6	-	-1.2	V
Y _{fs}	Forward transfer admittance	V _{DS} = -10V, I _D = -0.1A	-	220	-	mS
R _{DS(ON)}	Static drain-source on-state resistance	I _D = -100mA, V _{GS} = -4.0V	-	7	-	Ω
C _{iss}	Input capacitance	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz	-	28	-	pF
C _{oss}	Output capacitance	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz	-	5.2	-	pF
t _{ON}	Switching time	V _{DD} = -5V, I _D = -10mA V _{GS} = 0 ~ -5V	-	13	-	ns
t _{OFF}			-	135	-	

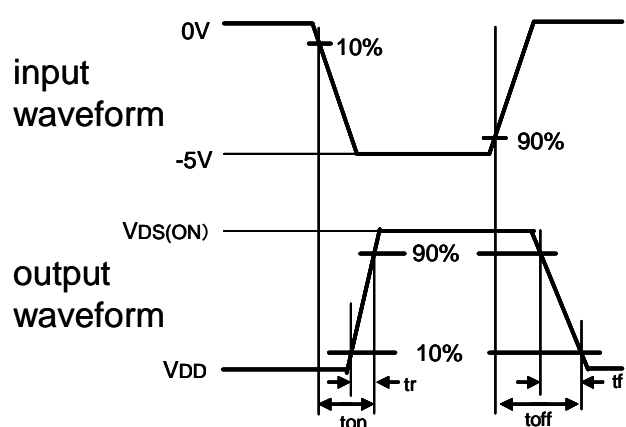
Switching time test condition

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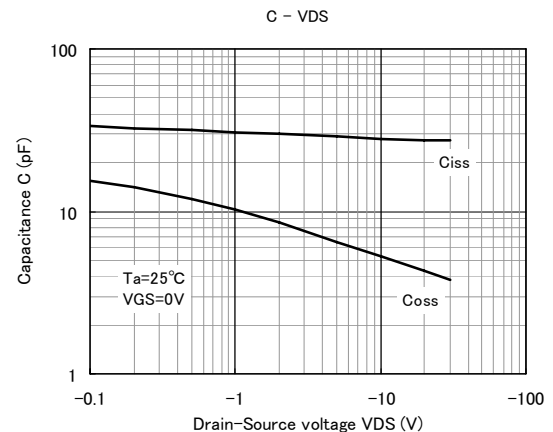
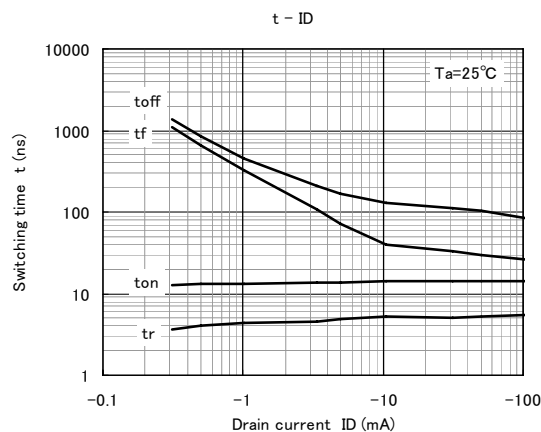
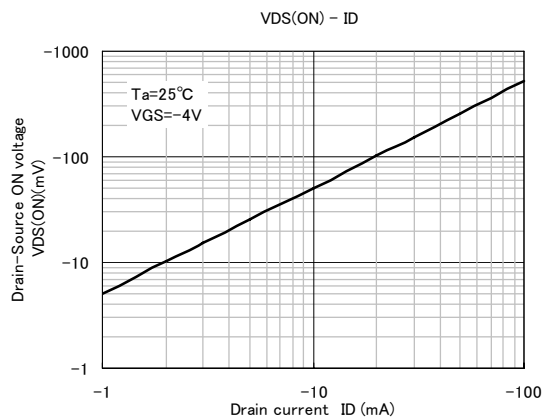
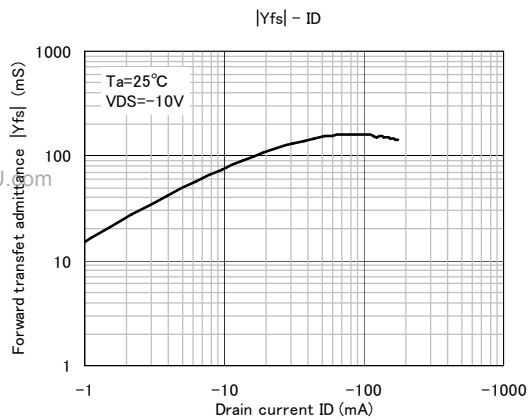
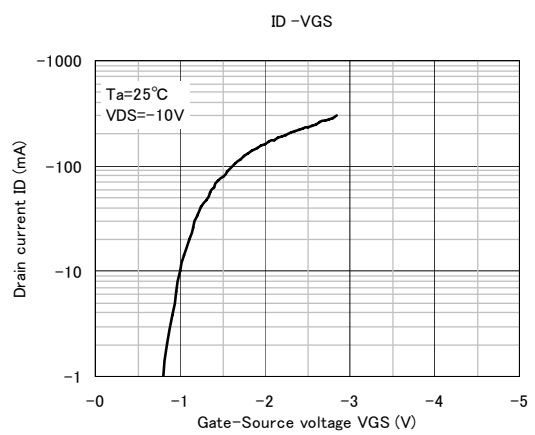
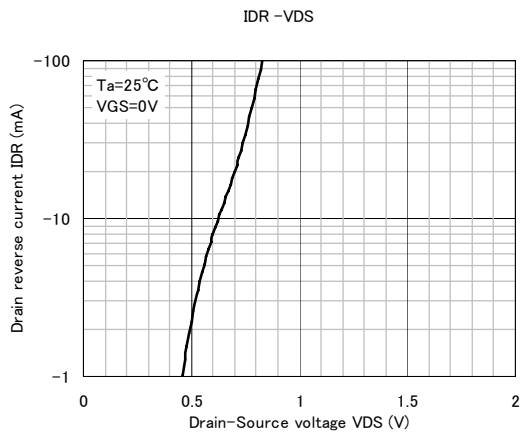
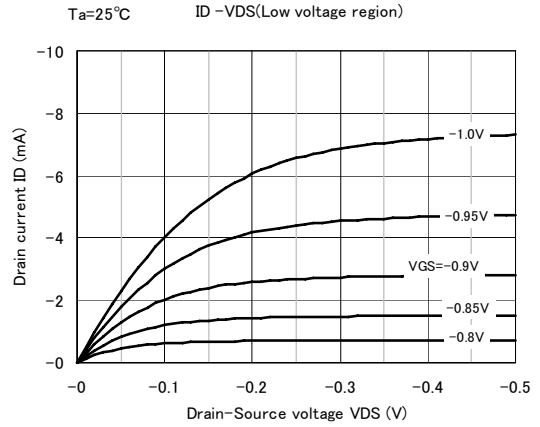
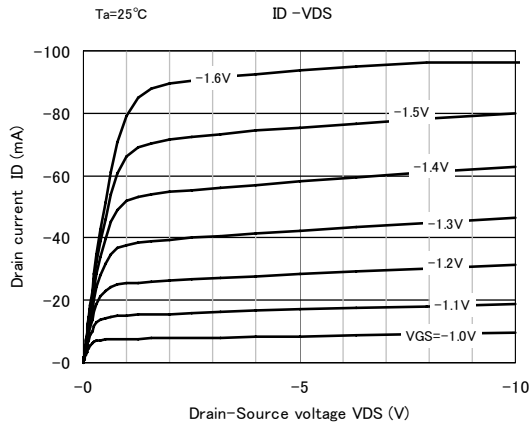
test circuit



input waveform



TYPICAL CHARACTERISTICS





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Keep safety first in your circuit designs!

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